



# DC to 5000 MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

Package: SOT-363

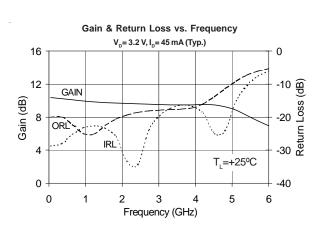




### **Product Description**

The SGA4163Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high  $F_T$  and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.





#### **Features**

- Broadband Operation: DC to 5000 MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

### **Applications**

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

Parameter	Specification			Unit	Condition	
rafameter	Min.	. Typ. Max.		UIIIL	Condition	
Small Signal Gain	9.5	10.5	11.5	dB	850MHz	
		9.7		dB	1950MHz	
		9.6		dB	2400MHz	
Output Power at 1dB Compression		13.0		dBm	850MHz	
		12.1		dBm	1950MHz	
Output Third Intercept Point		29.7		dBm	850MHz	
		25.4		dBm	1950MHz	
Bandwidth Determined by Return Loss		5000		MHz	>10dB	
Input Return Loss		28.0		dB	1950MHz	
Output Return Loss		20.1		dB	1950MHz	
Noise Figure		5.0		dB	1950MHz	
Device Operating Voltage	2.9	3.2	3.5	V		
Device Operating Current	41	45	49	mA		
Thermal Resistance (Junction - Lead)		255		°C/W		

Test Conditions:  $V_S = 8V$ ,  $I_D = 45$  mA Typ., OIP<sub>3</sub> Tone Spacing = 1MHz,  $P_{OUT}$  per tone = -5dBm,  $R_{BIAS} = 110\Omega$ ,  $T_L = 25$  °C,  $Z_S = Z_L = 50\Omega$ 



#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Max Device Current (I <sub>D</sub> )	90	mA
Max Device Voltage (V <sub>D</sub> )	5	V
Max RF Input Power	+18	dBm
Max Junction Temp (T <sub>J</sub> )	+150	°C
Operating Temp Range (T <sub>L</sub> )	-40 to +85	°C
Max Storage Temp	+150	°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:  $I_DV_D < (T_J - T_L) / R_{TH}, j - I$ 



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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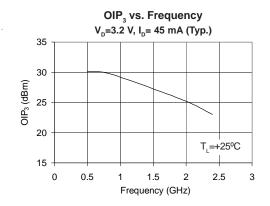


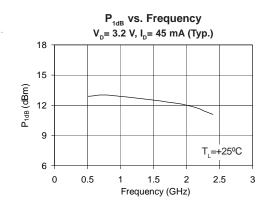
RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Typical Performance at Key Operating Frequencies

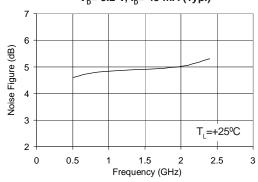
Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain	dB	10.3	10.2	10.5	9.7	9.6	9.4
Output Third Order Intercept Point	dBm		30.2	29.7	25.4	23.0	
Output Power at 1dB Compression	dBm		12.9	13.0	12.1	11.1	
Input Return Loss	dB	29.1	26.7	23.7	28.0	36.7	16.6
Output Return Loss	dB	19.7	20.8	24.3	20.1	18.7	17.6
Reverse Isolation	dB	15.5	16.0	16.3	17.2	17.6	18.4
Noise Figure	dB		4.6	4.8	5.0	5.3	

Test Conditions:  $V_S = 8V$ ,  $I_D = 45$  mA Typ.,  $OIP_3$  Tone Spacing = 1MHz,  $P_{OLIT}$  per tone = -5dBm,  $R_{BIAS} = 110\Omega$ ,  $T_L = 25$ °C,  $Z_S = Z_L = 50\Omega$ 



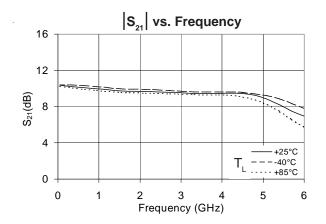


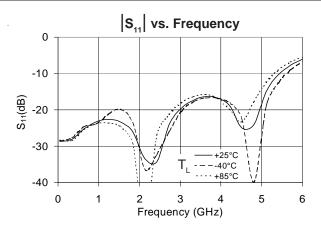
# Noise Figure vs. Frequency $V_D = 3.2 \text{ V}, I_D = 45 \text{ mA (Typ.)}$

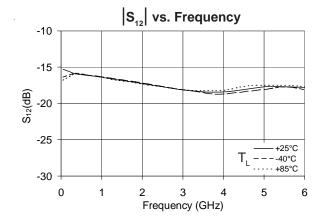


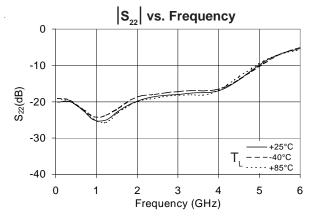


# Typical RF Performance Over Temperature ( Bias: $V_D = 3.2 \text{ V}, \ I_D = 45 \text{ mA (Typ.)}$ )





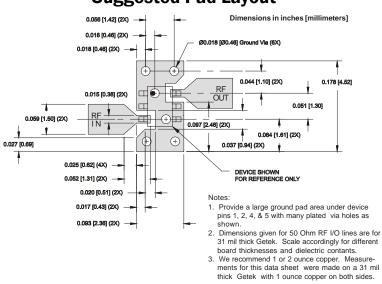






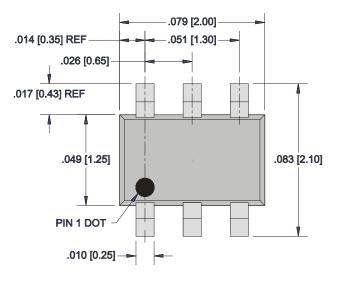
Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC-blocking capacitor chosen for the frequency of operation.
1, 2, 4, 5	GND	Connection to ground. For optimum RF performance, use via holes as close to ground leads as possible to reduce lead inductance.
6	RF OUT/BIAS	RF output and bias pin. DC voltage is present on this pin, therefor a DC-blocking capacitor is necessary for proper operation.

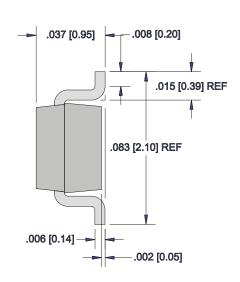
## **Suggested Pad Layout**



# **Package Drawing**

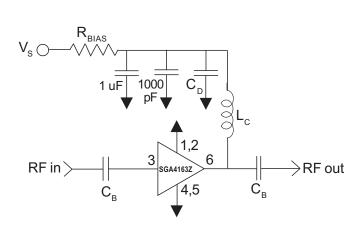
Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.







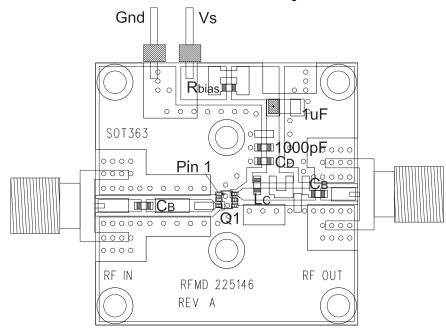
## **Application Schematic**



Reference	Frequency (Mhz)						
Designator	500	850	1950	2400	3500		
C <sub>B</sub>	220 pF	100 pF	68 pF	56 pF	39 pF		
C <sub>D</sub>	100 pF	68 pF	22 pF	22 pF	15 pF		
L <sub>c</sub>	68 nH	33 nH	22 nH	18 nH	15 nH		

Recommended Bias Resistor Values for $I_D = 45 \text{mA}$ $R_{BIAS} = (V_S - V_D) / I_D$				
Supply Voltage(V <sub>s</sub> )	6 V	8 V	10 V	12 V
$R_{BIAS}$ 62 Ω 110 Ω 150 Ω 200 Ω				
Note: R <sub>plas</sub> provides DC bias stability over temperature.				

## **Evaluation Board Layout**

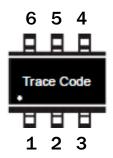


#### Mounting Instructions:

- 1. Use a large ground pad area near device pins 1, 2, 4, and 5 with many plated through-holes, as shown.
- 2. We recommend 1 or 2 ounces copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce cooper on both sides.



# **Part Identification Marking**



# **Ordering Information**

Ordering Code	Description			
SGA4163Z	7" Reel with 3000 pieces			
SGA4163ZSQ	Sample bag with 25 pieces			
SGA4163ZSR	7" Reel with 100 pieces			
SGA4163ZPCK1	850MHz, 8V Operation PCBA with 5-piece sample bag			